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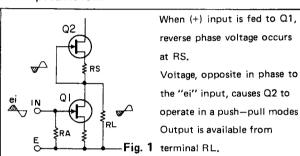
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■ POWER AMP SECTION CIRCUIT SYSTEM		type all stage				
	direct coupled		DAMPING FACTOR		FILTERS	
DYNAMIC POWER (IHF, 85	mentary SEPP (DAMPING FACTOR (1kHz, 8Ω)	70	Low	20Hz, 70Hz (12dB/oct.)
OUTPUT	2}200W	d pure comple- OCL circuit		70 100dB		20Hz, 70Hz (12dB/oct.) 6kHz, 12kHz (6dB/oct.) Continuous loudness control to
20Hz~20kHz Both Channels Driven	20Hz ~ 20kHz	OCL circuit	(1kHz, 8Ω) S/N RATIO	100dB -Amp + Power Amp)	Low High LOUDNESS CONTROL	6kHz, 12kHz (6dB/oct.)
		70W x 2 85W x 2	(1kHz, 8Ω) S/N RATIO (IHF, A Network)	100dB	Low High	6kHz, 12kHz (6dB/oct.) Continuous loudness control to
11-11-10-sh Channala Dain	20Hz \sim 20kHz B Class, 8Ω B Class, 4Ω A Class, 8Ω	OCL circuit 70W x 2	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre	100dB -Amp + Power Amp)	Low High LOUDNESS CONTROL S/N RATIO	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB
1kHz (Both Channels Driv	20Hz \sim 20kHz B Class, 8Ω B Class, 4Ω A Class, 8Ω	70W x 2 85W x 2	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω , Pre	100dB -Amp + Power Amp)	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network)	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve
1kHz Both Channels Driv	$\begin{array}{c} \text{20Hz} \sim \text{20kHz} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 4\Omega \\ \text{A Class, } 8\Omega \\ \text{ven)} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 4\Omega \\ \text{B Class, } 4\Omega \end{array}$	70W x 2 85W x 2 15W x 2 75W x 2 100W x 2	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic.	6kHz, 12 kHz $(6$ dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ $(100$ kΩ $(10$
1 kHz Both Channels Drive	$\begin{array}{l} \text{20Hz} \sim \text{20kHz} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 4\Omega \\ \text{A Class, } 8\Omega \\ \text{ven)} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \text{an)} \end{array}$	70W × 2 85W × 2 15W × 2 75W × 2 100W × 2 15W × 2	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM	100dB -Amp + Power Amp} 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp.	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB $50k\Omega,100k\Omega80dB$ $80dB$ $70dB$ $90dB$
	$\begin{array}{c} \text{20Hz} \sim \text{20kHz} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 4\Omega \\ \text{A Class, } 8\Omega \\ \text{ven)} \\ \text{B Class, } 8\Omega \\ \text{d Class, } 8\Omega \\ \text{n} \\ \text{B Class, } 8\Omega \\ \text{n} \\ \text{B Class, } 8\Omega \\ \text{n} \\ \text{n} \\ \text{B Class, } 8\Omega \\ \end{array}$	70W × 2 85W × 2 15W × 2 15W × 2 75W × 2 100W × 2 15W × 2	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape	6kHz, 12 kHz $(6$ dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100 kΩ 80 dB 80 dB 70 dB 90 dB
1kHz (One Channel Drive	$\begin{array}{c} \text{20Hz} \sim \text{20kHz} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \text{ven)} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \end{array}$	70W × 2 85W × 2 15W × 2 75W × 2 100W × 2 15W × 2	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (V	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 κΩ, 100κΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter system) Voltage direction relay drive system)
1kHz (One Channel Drive	$\begin{array}{c} \text{20Hz} \sim \text{20kHz} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \text{ven)} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \end{array}$	70W × 2 85W × 2 15W × 2 15W × 2 75W × 2 100W × 2 15W × 2 80W 100W	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type DIMPEDANCE MIC 200μV/100Ω	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (V Operation Switch	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem)
1kHz (One Channel Drive TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output	$\begin{array}{c} \text{20Hz} \sim \text{20kHz} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \text{ven)} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \end{array}$	70W × 2 85W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND	100dB -Amp + Power Amp} 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type D IMPEDANCE	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (V	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 κΩ, 100κΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter system) Voltage direction relay drive system)
1kHz (One Channel Drive TOTAL HARMONIC DISTO B Class at Rated Output A Class at Rated Output	$\begin{array}{c} \text{20Hz} \sim \text{20kHz} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \text{ven)} \\ \text{B Class, } 8\Omega \\ \text{B Class, } 8\Omega \\ \text{A Class, } 8\Omega \\ \end{array}$	70W × 2 85W × 2 15W × 2 15W × 2 75W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphane Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type DIMPEDANCE MIC 200μV/100Ω 3mV/50kΩ, 100kΩ 3mV/50kΩ	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (N Operation Switch Tape Dubbing Switch Continuous Loudness	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 κΩ, 100κΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter system) Voltage direction relay drive system)
1kHz (One Channel Drive TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST	20Hz ~ 20kHz B Ciass, 8Ω B Ciass, 4Ω A Class, 8Ω ven) B Ciass, 4Ω A Class, 8Ω B Class, 4Ω C A Class, 8Ω B Class, 4Ω A Class, 8Ω	70W × 2 85W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type DIMPEDANCE MIC 200μV/100Ω 3mV/50kΩ, 100kΩ 3mV/50kΩ 310mVrms (870mVp-p)	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (V Operation Switch Tape Dubbing Switch	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover
TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz:7kHz=4:1)	20Hz ~ 20kHz B Ciass, 8Ω B Ciass, 4Ω A Class, 8Ω ven) B Ciass, 4Ω A Class, 8Ω B Class, 4Ω C A Class, 8Ω B Class, 4Ω A Class, 8Ω	70W × 2 85W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.19 0.02%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphane Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity Instal 1kHz Mic.	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200μV/100Ω 3mV/50kΩ 310mVrms (870mVp-p) 2.5mV/50kΩ	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (N Operation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover
1kHz (One Channel Drive TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz:7kHz~4:1) B Class at Rated Power B Class at 1W	20Hz ~ 20kHz B Ciass, 8Ω B Ciass, 4Ω A Class, 8Ω ven) B Ciass, 4Ω A Class, 8Ω B Class, 4Ω C A Class, 8Ω B Class, 4Ω A Class, 8Ω	70W × 2 85W × 2 15W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200μV/100Ω 3mV/50kΩ, 100kΩ 310mVrms (870mVc-p) 2.5mV/50kΩ 120mV/40kΩ	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (V Operation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption Rated	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz
TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz: 7kHz=4:1) B Class at Rated Power	20Hz \sim 20kHz \sim 20kHz B Class, 8 Ω B Class, 4 Ω A Class, 8 Ω ver) B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω A Class, 8 Ω CRTION	70W × 2 85W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphane Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200μV/100Ω 3mV/50kΩ, 100kΩ 310mVrms (870mVrp) 2.5mV/50kΩ 120mV/40kΩ 120mV/40kΩ	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (N Operation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover
TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz:7kHz~4:1) B Class at Rated Power B Class at 1W A Class at Rated Power A Class at Rated Power	20Hz \sim 20kHz \sim 20kHz B Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 8 Ω B Class, 8 Ω Class, 8 Ω B Class, 8 Ω CRTION	70W × 2 85W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IM Tape REC Out A, B	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200μV/100Ω 3mV/50kΩ 310mVrms (870mVc-p) 2.5mV/50kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ PEDANCE 120mV/40kΩ	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circuit (V Operation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL EXCEPT U.S. &	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA
TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz: 7kHz=4:1) B Class at Rated Power B Class at Rated Power A Class at 1W A Class at 1A	20Hz \sim 20kHz \sim 20kHz B Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 8 Ω B Class, 8 Ω Class, 8 Ω B Class, 8 Ω CRTION	70W × 2 85W × 2 15W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02% 0.1% 10.05% 0.1% 10.05% 0.1% 10.05%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IM	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type DIMPEDANCE MIC 200μV/100 Ω 3mV/50k Ω , 100k Ω 3mV/50k Ω 310mVrms (870mVρ-p) 2.5mV/50k Ω 120mV/40k Ω 120mV/40k Ω 120mV/40k Ω	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (V Operation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 κΩ, 100κΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA 250W 420W
TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz:7kHz~4:1) B Class at Rated Power B Class at 1W A Class at Rated Power A Class at Rated Power H Class at Rated Power Class at 1W Class	20Hz ~ 20kHz B Class, 8Ω B Class, 4Ω A Class, 8Ω A Class, 8Ω C C C C C C C C C C C C C C C C C C C	70W × 2 85W × 2 15W × 2 100W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.19 0.02%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IM Tape Rec Out A, B Pre Out	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type DIMPEDANCE MIC 200μV/100Ω 3mV/50kΩ, 100kΩ 3mV/50kΩ 310mVrms (870mVp-p) 2.5mV/50kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 775mV/2kΩ	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (N Operation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL EXCEPT U.S. & CANADIAN MODELS	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA 250W 420W Switched (2) Max. 200W
TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz:7kHz~4:1) B Class at Rated Power B Class at 1W A Class at Rated Power A Class at Rated Power	20Hz \sim 20kHz \sim 20kHz B Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω Class, 8 Ω Class, 8 Ω Correction B Class, 8 Ω RTION	70W × 2 85W × 2 15W × 2 15W × 2 15W × 2 15W × 2 16W × 2 16W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02% 0.1% 10.05% 0.1% 10.05% 0.1% 10.05% 10.05%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IMI Tape Rec Out A, B Pre Out FREQUENCY RESPONSE	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200μV/100Ω 3mV/50kΩ 3mV/50kΩ 10mV/ms (870mVp-p) 2.5mV/50kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ 120mV/40kΩ	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protection Circuit (Noperation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL EXCEPT U.S. & CANADIAN MODELS Max. AC Outlets	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA 250W 250W 250W Switched (2) Max. 200W Unswitched (2) Max. 200W
TOTAL HARMONIC DISTO B Class at Rated Output B Class at Rated Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz:7kHz=4:1) B Class at Rated Power B Class at 1W A Class at 1W Class at Rated Power A Class at 1W POWER BANDWIDTH (IHF, Both Channels Driven of the Class at 1W FREQUENCY RESPONSE B Class A Class	20Hz ~ 20kHz B Class, 8Ω B Class, 4Ω A Class, 8Ω P Class, 8Ω B Class, 4Ω A Class, 8Ω B Class, 4Ω A Class, 8Ω A Class, 8Ω A Class, 8Ω CORTION Less than Less	70W × 2 85W × 2 15W × 2 15W × 2 15W × 2 15W × 2 16W × 2 16W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02% 0.1% 10.05% 0.1% 10.05% 0.1% 10.05% 10.05%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IM Tape Rec Out A, B Pre Out FREQUENCY RESPONSE Phono (RIAA equalizati Mic. Tuner, Aux, Tape PB	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200 μ V/100 Ω 3mV/50 κ Ω, 100 κ Ω 310mVrms (870mVp-p) 2.5mV/50 κ Ω 120mV/40 κ Ω 120mV/2 κ Ω 775mV/2 κ Ω 700)	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (V Operation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL EXCEPT U.S. & CANADIAN MODELS Max.	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA 250W 420W Switched (2) Max. 200W
TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz: 7kHz=4:1) B Class at Rated Power B Class at 1W A Class at Rated Power A Class at 1W POWER BANDWIDTH (IHF, Both Channels Driven 1) FREQUENCY RESPONSE B Class	20Hz \sim 20kHz \sim 20kHz B Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω Class, 8 Ω Class, 8 Ω Correction B Class, 8 Ω RTION	70W × 2 85W × 2 15W × 2 15W × 2 15W × 2 15W × 2 16W × 2 16W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02% 0.1% 10.05% 0.1% 10.05% 0.1% 10.05% 10.05%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IM Tape Rec Out A, B Pre Out FREQUENCY RESPONSE Phono (RIAA equalizati Mic.	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type DIMPEDANCE MIC $200\mu V/100\Omega$ $3mV/50k\Omega$, $100k\Omega$ $3mV/50k\Omega$, $100k\Omega$ $3mV/50k\Omega$, $100k\Omega$ $12mV/40k\Omega$, $120mV/40k\Omega$, 12	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protection Circuit (Noperation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL EXCEPT U.S. & CANADIAN MODELS Max. AC Outlets	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA 250W 250W 250W Switched (2) Max. 200W Unswitched (2) Max. 200W
TOTAL HARMONIC DISTO B Class at Rated Output B Class at Rated Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz:7kHz=4:1) B Class at Rated Power B Class at 1W A Class at 1W POWER BANDWIDTH (IHF, Both Channels Driven of the Class at 1W FREQUENCY RESPONSE B Class A Class INPUT SENSITIVITY B Class A Class	20Hz \sim 20kHz \sim 20kHz B Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω Class, 8 Ω Class, 8 Ω Correction B Class, 8 Ω RTION	70W × 2 85W × 2 15W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02% 0.1% 10.05% 5Hz ~ 50kHz 5Hz ~ 100kHz 12 ± 10dB 12 ± 10dB 775mV 330mV	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IM Tape Rec Out A, B Pre Out FREQUENCY RESPONSE Phono (RIAA equalizati Mic. Tuner, Aux, Tape PB TONE CONTROLS Bass	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200 μ /100 Ω 3mV/50 κ Ω, 100 κ Ω 3mV/50 κ Ω, 100 κ Ω 310mVrms (870mV ρ -p) 2.5mV/50 κ Ω 120mV/40 κ Ω 120mV/2 κ Ω 775mV/2 κ Ω 30Hz ~ 15 κ Hz ±0.2dB 20Hz ~ 20 κ Hz +0.5dB, -1dB 50Hz ±15dB 250Hz, 500Hz ±3dB	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (N Operation Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL EXCEPT U.S. & CANADIAN MODELS Max. AC Outlets DIMENSIONS WEIGHT	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ80dB 80dB 70dB 90dB S cuit (ASO detection limiter system) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA 250W 250W 420W Switched (2) Max. 200W Unswitched (2) Max. 200W 436(W) x 144(H) x 323m/rn (D) 15.5kg
TOTAL HARMONIC DISTO B Class at Rated Output B Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz:7kHz=4:1) B Class at Rated Power B Class at Rated Power A Class at Rated Power A Class at 1W POWER BANDWIDTH (IHF, Both Channels Driven of the Class at 1W) FREQUENCY RESPONSE B Class A Class INPUT SENSITIVITY B Class	20Hz \sim 20kHz \sim 20kHz \sim 20kHz \sim 20kHz \sim 8 Class, 8 Ω A Class, 8 Ω B Class, 8 Ω B Class, 8 Ω A Class, 8 Ω B Class, 8 Ω A Class, 8 Ω Class, 8 Ω Correction Resolution Resol	70W × 2 85W × 2 15W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02% 0.1% 10.05% 0.1% 10.05%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre ■ PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY ANE Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IM Tape Rec Out A, B Pre Out FREQUENCY RESPONSE Phono (RIAA equalizati Mic. Tuner, Aux, Tape PB TONE CONTROLS	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200μV/100 Ω 3mV/50k Ω , 100k Ω 3mV/50k Ω , 100k Ω 310mVrms (870mVp-p) 2.5mV/50k Ω 120mV/40k Ω 120mV/40k Ω 120mV/40k Ω 120mV/40k Ω 120mV/40k Ω 120mV/40k Ω 120mV/2k Ω 775mV/2k Ω ion) 30Hz \sim 15kHz ±0.2dB 20Hz \sim 20kHz +0.5dB, $-$ 1dB 50Hz ±15dB	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (N Operation Switch Tape Dubbing Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL EXCEPT U.S. & CANADIAN MODELS Max. AC Outlets	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA 250W 250W 420W Switched (2) Max. 200W Unswitched (2) Max. 200W 436(W) x 144(H) x 323m/rm (D) 15.5kg
TOTAL HARMONIC DISTO B Class at Rated Output B Class at Rated Output A Class at 1W Output A Class at 1W Output A Class at 1W INTERMODULATION DIST (70Hz: 7kHz=4:1) B Class at Rated Power B Class at Rated Power A Class at 1W POWER BANDWIDTH (IHF, Both Channels Driven (IMF, Both Channels Driven (IMF)) FREQUENCY RESPONSE B Class A Class INPUT SENSITIVITY B Class INPUT MERCANCE	20Hz \sim 20kHz \sim 20kHz B Class, 8 Ω B Class, 4 Ω A Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω B Class, 8 Ω Class, 8 Ω Class, 8 Ω Correction B Class, 8 Ω RTION	70W × 2 85W × 2 15W × 2 15W × 2 15W × 2 100W × 2 15W × 2 80W 100W 15W 0.1% 0.04% 0.1% 0.02% 0.1% 10.05% 0.1% 10.05%	(1kHz, 8Ω) S/N RATIO (IHF, A Network) Residual Noise (8Ω, Pre PRE-AMP SECTION CIRCUIT SYSTEM Equalizer Amp Microphone Amp Control Amp INPUT SENSITIVITY AND Phono 1 Phono 2 Phono Maximum Input Capacity (at 1kHz) Mic. Tuner Aux. 1, 2 Tape PB A, B OUTPUT LEVER AND IM Tape Rec Out A, B Pre Out FREQUENCY RESPONSE Phono (RIAA equalizati Mic. Tuner, Aux, Tape PB TONE CONTROLS Bass	100dB -Amp + Power Amp) 0.8mV FET, SRPP Input Tr. SEPP Output Two-transistor direct coupled amp. Intermediate emitter-follower type 0 IMPEDANCE MIC 200μV/100 Ω 3mV/50k Ω 3mV/50k Ω 310mVrms (870mVp-p) 2.5mV/50k Ω 120mV/40k Ω 120mV/40k Ω 120mV/40k Ω 120mV/40k Ω 120mV/40k Ω 20mV/2k Ω 775mV/2k Ω on) 30Hz \sim 15kHz ±0.2dB 20Hz \sim 20kHz +0.5dB, $-$ 2dB 10Hz \sim 50KHz ±15dB 250Hz ±15dB 250Hz ±3dB	Low High LOUDNESS CONTROL S/N RATIO (IHF, A Network) Phono 1 Phono 2 Mic. Tuner, Aux, Tape AUXILIARY CIRCUITS Transistorized Protector Circ Speaker Protection Circuit (N Operation Switch Continuous Loudness GENERAL Power Source Power Consumption Rated CANADIAN MODEL U.S. MODEL EXCEPT U.S. & CANADIAN MODELS Max. AC Outlets DIMENSIONS WEIGHT	6kHz, 12kHz (6dB/oct.) Continuous loudness control to be treated as loudness curve MC 70dB 50 kΩ, 100kΩ 80dB 80dB 70dB 90dB S cuit (ASO detection limiter sy stem) Voltage direction relay drive system) A Class/B Class switchover AC 110, 117, 130, 220, 240 V 50 ~ 60Hz 320W 400VA 250W 250W 420W Switched (2) Max. 200W Unswitched (2) Max. 200W 436(W) x 144(H) x 323m/rm (D) 15.5kg

CIRCUIT DESCRIPTIONS

SRPP (SHUNT-REGULATED PUSH-PULL) CIR-CUIT

Features: Thanks to efficient use of power this circuit features a large dynamic range. Superior frequency response, lower noise and distortion ratio in following stages due to higher output impedance.

The SRPP circuit provided the above features to pre-amps during the tube era. It is composed of DC elements in series, but if we look at it as an AC circuit from the load side, the top and bottom elements appear to be AC, connected in parallel, so that the input impedance is high and output impedance low.



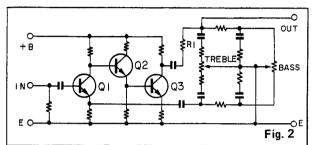
In this circuit Q2 serves as load resistance for Q1 by using the gain from the FET's high output impedance. Furthermore, it is designed for a high RL factor. This is to handle the high gain with less distortion. In addition to a low distortion ratio, high S/N ratio, large input capacity and precise RIAA characteristics, the CA-1000 equalizer amp is not influenced by broadcast signals even in high field strength areas, and will accept various types of cartridges. These features are all assured by the primary FET stage. Because these elements provides characteristics close to those assured by squared factors, that random harmonic distortion is reduced and noise characteristics, especially pulse noise is ex-Noise factor in the transistortremely low. collector current is minimal (near $10\mu A$), so that ideally the equalizer amp primary stage current should be near this figure, except that this would make it difficult to provide sufficient input power. Drain current does not affect this figure, either, so it can be decreased by the supply of more current.

The CA-1000 is designed for 1mA drain current, so that primary amp stage input is dozens of times greater than the transistor's 10μ A.

These excellent FETs were not used in high-fidelity amplifiers until now because of their smaller gain per unit, and because the IDSS (gate shutoff current) scatter was too large. It has also been difficult to

gather data on the best characteristics for tube and transistor systems, yet this unit uses a combination of two selected FETs in the SRPP circuit for outstanding performance characteristics.

2. SPECIAL YAMAHA TONE CONTROL SYSTEM This circuit is composed of a CR damping circuit, used generally in audio equipment, of the negative feed back type.



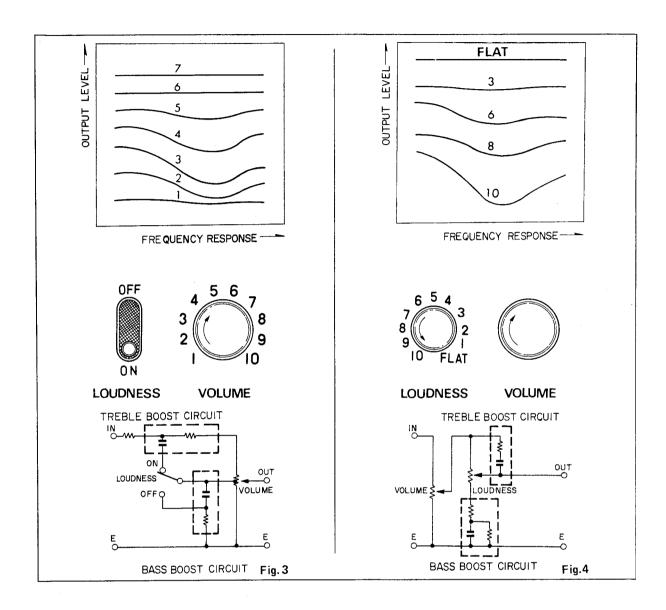
When the treble from the circuit shown in the figure is boosted, the parallel-coupled impedance in the first stage Q1 emitter rises in range and is reduced in amount. In other words, the NF decreases, boosting the treble tones. On the other hand, to cut the treble a special treble damping effect is produced by lowering the impedance of the contact point between the R1 (connected to the last stage collector) and the output terminal. Bass tone control is carried out in the same way. Because the CA-1000 is the same as the first-quality

Because the CA-1000 is the same as the first-quality three-stage direct-coupled equalizer amplifiers used in the most expensive audio equipment, the S/N ratio is superb and distortion is almost unmeasurably low. In addition, when the tone controls are set for flat response, gain at 25dB is 50dB negative feedback for outstanding stability.

3. CONTINUOUS LOUDNESS CIRCUIT

The continuous loudness circuit used in the CA-1000 corrects the weak point found in conventional loudness controls; its effect is graduated according to the volume control setting for ideal loudness characteristics at any volume level.

A conventional loudness circuit, as shown in the figure, is a time constant circuit connected to the middle volume tap. Its characteristics are changed according to the volume control setting as shown in Fig. 3, but it is impossible to adjust it to match speaker performance or room acoustics. The continuous loudness circuit in the CA-1000, however, is a circuit connected behind the volume circuit (actually, behind the tone control circuit). This solves the above problem, allowing the listener to use the circuit to achieve ideal listening characteristics. (Fig. 4)



4. A CLASS AND B CLASS OPERATION

The trend today is toward amplifiers with larger and larger output power, and this is one of the most important themes in new product development. Almost 100% (except for a few exceptions) of the solid state hi-fi amps now on sale employ B Class (strictly speaking, AB Class) operation. Yet engineers trying to combat audio distortion are constantly troubled by the crossover distortion and notch distortion present in B Class amps.

In the CA-1000 a great deal of effort has been spent to decrease high-range distortion while maintaining sufficient negative feedback stability. As a result, distortion between 20Hz and 100kHz has been reduced to less than 0.015% (Fig. 5). Only in A

Class amps can one find higher stability, better performance and lower crossover or notch distortion. (Fig.6)

An A Class amp. is only common sense when one wants a small signal circuit, while the B Class is for high power. The B Class amp. boasts higher efficiency, provides relatively more output than the capacity loss in its power transistors, has lower ripple due to reduced current at no signal, has a better S/N ratio and is less sensitive to heat than the A Class amp. Nevertheless, the A Class amp. has its own merits, even through it suffers by comparison to a B Class amp. in the above ways when used as a main amp: in effect, the A Class amp. is more

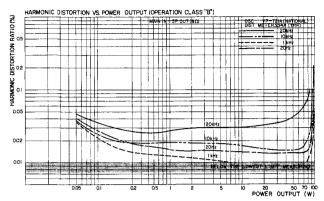


Fig. 5

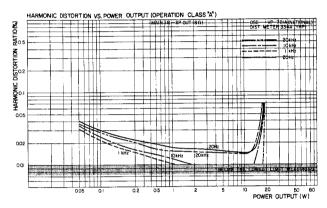
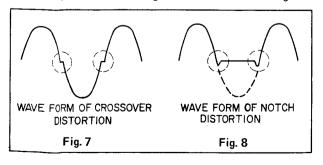


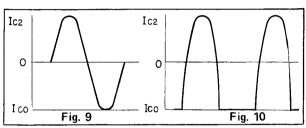
Fig. 6

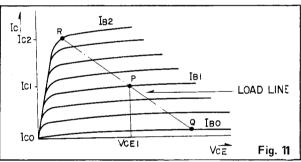
faithful to the original signal. In other words, this system is much less susceptible to unstable performance and hence inferior tone quality. There is theoretically no crossover or notch distortion, and sharply reduced high range distortion. Let us examine crossover and notch distortion more carefully. Crossover distortion occurs if there is no signal current flow at the instant of changeover between positive and negative in a given cycle, during the B Class push-pull operation. In other words, when one transistor is changing from On to Off, the other transistor will be a bit late in switching from Off to On, as shown in Fig. 7. This is caused by nonlinearity in the signal transfer characteristics when the transistor collector current is small. To minimize this problem an idling current has been designed.



Notch distortion refers to the pulse distortion illustrated in Fig. 8. It occurs because of incomplete transistor switching, and is one of the most difficult problems inherent to solid state amplifiers. The high frequency elements of this distortion are also $5\sim10$ times the 2nd harmonic or even higher than the audible range.

Finally, let us examine the differences between A Class and B Class amps in theory. The difference for classification purposes is in the bias setting. In an A Class amp, the mid-point P is set as the operation point where the direct load, drawn from the transistor static characteristics, is divided into two. Transistor base bias current is IB1 when there is no input



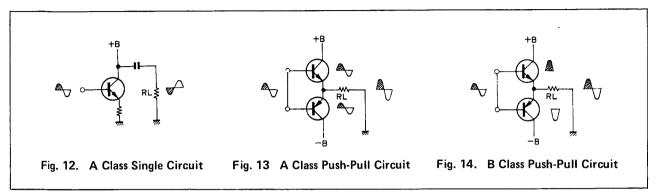


signal, as shown in Fig. 11, and IC1 is continually flowing in the collector. Between the collector and emitter voltage VCE1 is added. Add a sine wave input signal to this transistor and then, when the base current is deflected from IBO to IB2 collector current changes from ICO to IC2 and a sine wave current with maximum amplitude IC2-IC0 is provided as shown in Fig. 9. In this way, when the amplifier output waveform operates for full negative and positive waves of the input signal, the operation is called A Class. In contrast with this, when the transistor bias is the base current IBO and set to point Q to cut off practically all the collector current, then when a sine wave input signal, causing maximum deflection in IB2, is added, base current is deflected from IBO to IB2 for half the wave, but for the other half it does not flow due to opposite bias. For this reason the collector current changes o the performance shown in Fig. 10, Only following during one half of each input sinewave. operation, using only half the input waveform, is

called B Class amplification.

A Class amplification is basically single operation, but output is only 2~3W; therefore a push-pull circuit is used for larger output. B Class operation,

as shown above, is amplification using only half the waveform. Therefore, to get a full waveform the push-pull circuit is also used here. See Figs. 12~14.



5. PROTECTION CIRCUITS

■ Transistor Protection Circuit

The transistor protection circuit guards against transistor damage due to excessive current from a load short. In the CA-1000 a Darlington connection is used to regulate the input power flowing to the power transistor. This system has the advantage of working very quickly and protecting the transistor against overload by acting within an average of μ second. This circuit checks both power transistor emitter resistance voltage and collector voltage drop, regulating the power transistor drive signal via the control transistor. When the load resistance drops below 4Ω the power transistor current is cut, which also radically lowers the output power for transistor protection. If there is a complete short in the output terminal, the current flowing in the power transistor averages 1.3A. To aid in discovering the cause of the short, the power does not go completely off; output merely drops considerably.

■ Speaker Protection Circuit

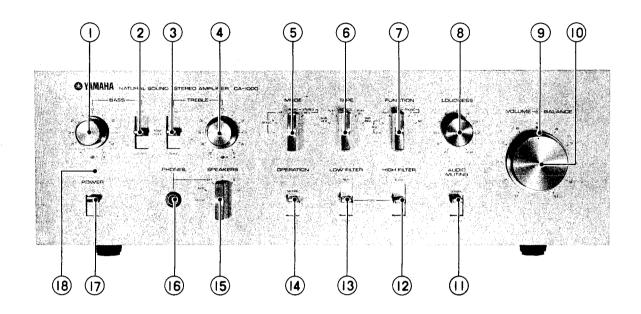
Note: Refer to the general circuit diagram power circuit.

This protection system is also unique to Yamaha. When (+) DC electric potential appears at either the left or right output terminal, the TR707 base is affected by the bias so that this transistor will be on, while TR708 and 709 will be off. Therefore the relay circuit goes off to protect the speakers.

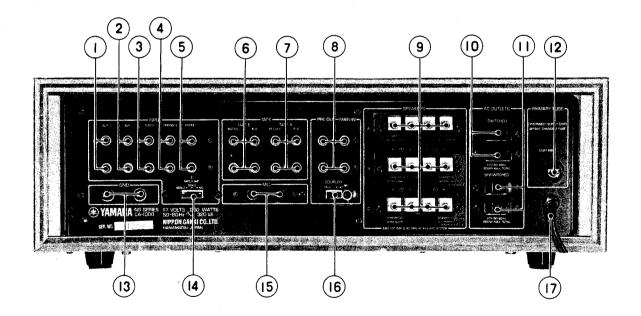
If there is a (–) DC electric potential, TR705 and 706 go on and operate in the same way. To avoid unpleasant shock noise when the switch is turned on a muting circuit is provided. This circuit switches on due to electric potential gain from the mid-point of the power sheet +B D704 and D706, with the time constant controlled by C715 and R721. After 4~5 seconds the TR709 base potential turns the transistor on, at the same time turning TR708 on and powering the relay.

EXTERNAL VIEW

FRONT PANEL



REAR PANEL



FRONT PANEL

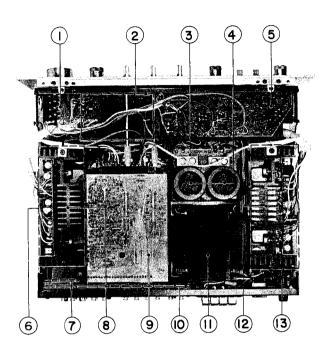
- BASS TONE CONTROL
- BASS TURNOVER SWITCH
- **3** TREBLE TURNOVER SWITCH
- **4** TREBLE TONE CONTROL
- **6** MODE SELECTOR
- **6** TAPE SELECTOR
- FUNCTION SELECTOR
- 8 LOUDNESS CONTROL
- BALANCE CONTROL
- O VOLUME CONTROL
- AUDIO MUTING SWITCH
- HIGH FILTER SWITCH
- 18 LOW FILTER SWITCH
- A CLASS/B CLASS OPERATION SWITCH
- SPEAKER SELECTOR
- **1** HEADPHONE JACK
- POWER SWITCH
- B PILOT LAMP

REAR PANEL

- AUX-2 INPUT JACKS
- 2 AUX-1 INPUT JACKS
- **3** TUNER INPUT JACKS
- 4 PHONO-2 (Turntable) INPUT JACKS
- 9 PHONO-1 (Turntable) INPUT JACKS
- **6** TAPE-B JACKS
- 7 TAPE-A JACKS
- 8 PRE OUT/MAIN IN JACKS
- SPEAKER TERMINALS
- AC OUTLETS (SWITCHED)
- AC OUTLETS (UNSWITCHED)
- PRIMARY FUSE
- **®** GROUND TERMINAL
- 1 INPUT IMPEDANCE SWITCH
- MICROPHONE JACKS
- 1 COUPLER SWITCH
- AC CORD

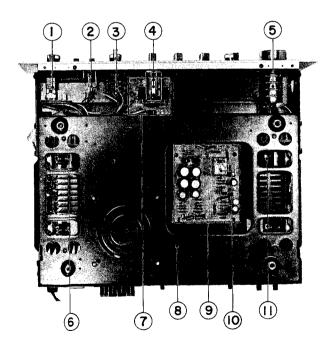
INTERNAL VIEW

TOP VIEW



- 1 ELECTROLYTIC CAPACITOR (NA06336)
- FILTER CIRCUIT BOARD (NA06338)
- ELECTROLYTIC CAPACITOR CIRCUIT BOARD (NA06352)
- 4 ELECTROLYTIC CAPACITOR (18,000µF/63WV)
- 5 TONE CONTROL CIRCUIT BOARD (NA06337)
- 6 MAIN AMP CIRCUIT BOARD
 - NA06331: EXCEPT EUROPEAN MODEL NA06388: EUROPEAN MODEL
- 7 MC AMP CIRCUIT BOARD (NA06339)
- **3**HEAT SINK
- 9 FUNCTION CIRCUIT BOARD (NA06335)
- PREAR PANEL CIRCUIT BOARD (NA06333)
- **POWER TRANSFORMER (GA60530)**
- MHEAT SINK
- MAIN AMP CIRCUIT BOARD

BOTTOM VIEW



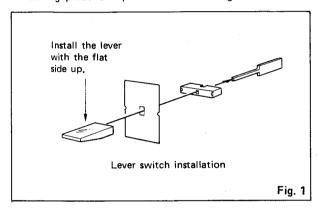
- 1 POWER SWITCH CIRCUIT BOARD
 - NA06375: EXCEPT EUROPEAN MODEL NA06376: EUROPEAN MODEL ONLY
- 2 HEADPHONE JACK
- SPEAKER SELECTOR
- **4** OPERATION SWITCH
- \bullet VARIABLE RESISTOR (Volume/Balance Control: HB250k Ω × 2 WITH CENTER CLICK A100k Ω × 2)
- 6 POWER TRANSISTOR
- OPERATION SWITCH CIRCUIT BOARD (NA06354)
- 8 CHASSIS
- 9 POWER CIRCUIT BOARD (NA06332)
- SPEAKER PROTECTION CIRCUIT RELAY (HC-2P)
- **1** POWER TRANSISTOR

PARTIAL DISASSEMBLY

BEFORE DISASSEMBLY

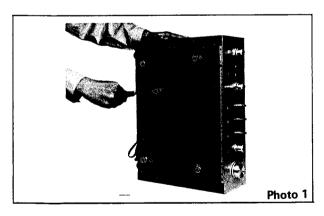
- The screwdriver for each screw should match the screw size. If you use a smaller or larger size it will damage the groove.
- If you use excessive force on the printed circuit board it will crack or cut the print wiring, so be careful.
- When using a soldering iron finish all work as quickly as possible.

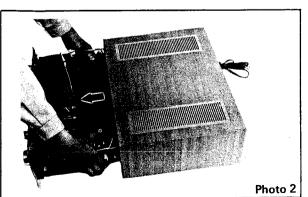
Be careful not to install switches and knobs in the wrong place or upside-down. See Fig. 1.



CABINET REMOVAL

- a. Remove screws 1~5 as shown in Photo 1.
- b. Remove the cabinet as shown in Photo 2.





MC AMP CIRCUIT BOARD REMOVAL

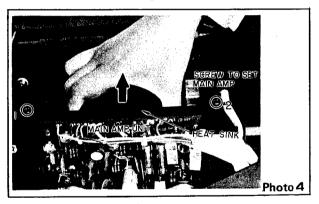
- a. Remove the two MC amp circuit board holder screws.
- b. Pull up the MC amp circuit board in the direction of the arrow as shown in Photo 3.



MAIN AMP UNIT REMOVAL

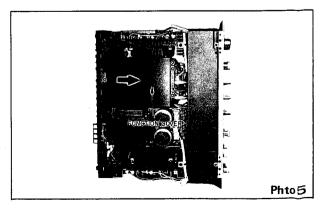
- a. Remove screws 1, 2 as shown in Photo 4.
- b. Pull up the main amp unit in direction of the arrow to remove it as shown in Photo 4.

Note: Be careful not to cut the lead cord connected to the main amp circuit board.

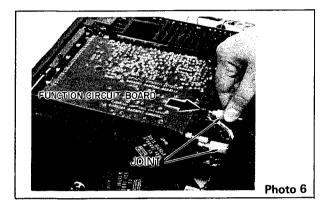


FUNCTION CIRCUIT BOARD

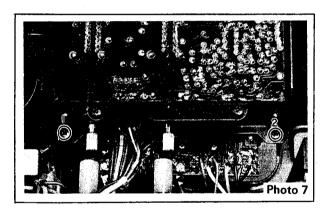
a. Loosen screws 1~3 and slide the function circuit board cover in the direction of arrow to remove it as shown in Photo 5.



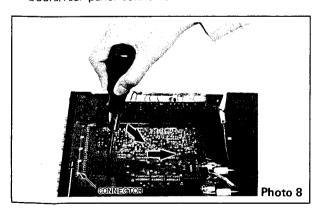
b. Slide the joints toward the front panel, then remove the function circuit board from the extention shaft as shown in Photo 6.



c. Loosen screws 1, 2 shown in Photo 7.

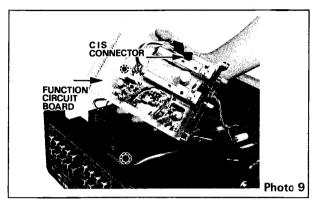


d. Insert a screwdriver into the hole in the function circuit board as shown in Photo 8 and pull in the direction of the arrow. Remove the function circuit board/rear panel connector.



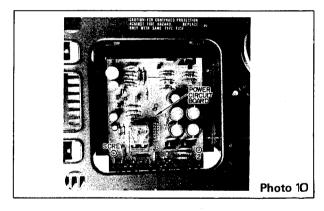
e. Remove the two CIS connectors from the rear panel and the one connected to the front panel, then remove the function circuit board as shown in Photo 9.

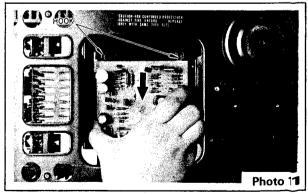
Note: When reinstalling the function circuit board, set the FUNCTION and TAPE switches to the same positions, then add the joint.



POWER CIRCUIT BOARD REMOVAL

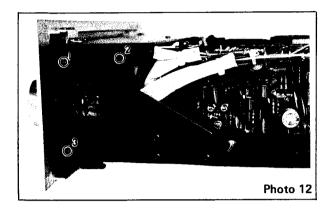
- a. Turn the chassis upside down.
- b. Remove screws 1, 2 shown in Photo 10, then slide the power circuit board in the direction of the arrow to remove it as shown in Photo 11.

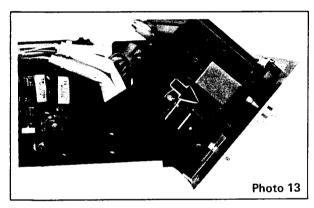




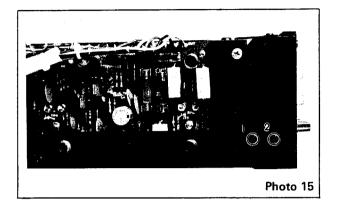
SUB CHASSIS UNIT TILTING

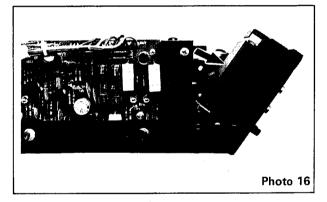
a. Remove screw 1 and loosen screws 2, 3 shown in Photo 12, then slide down the sub chassis unit as shown in Photo 13.





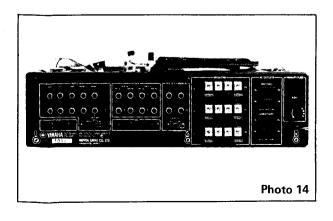
c. Remove screw 1 and loosen screw 2 shown in Photo 15,
 15, then tilt down the rear panel as shown in Photo 16.





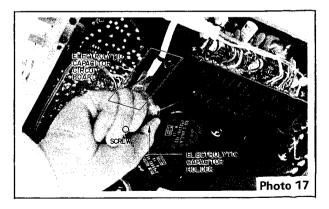
REAR PANEL TILTING

- a. Remove the function circuit board (refer to Photo $5\sim$ 9).
- b. Remove screws 1~3 shown in Photo 14.



ELECTROLYTIC CAPACITOR CIRCUIT BOARD REMOVAL

- a. Tilt the sub chassis unit down (refer to Photo 12, 13).
- b. Remove screw shown in Photo 17, then pull the electrolytic capacitor holder up and remove it.

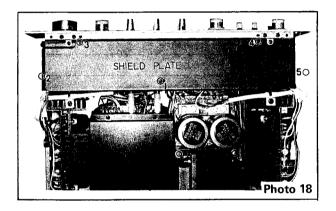


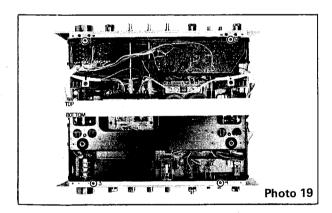
c. Slide the electrolytic capacitor circuit board toward the front panel, pull it up and remove it.

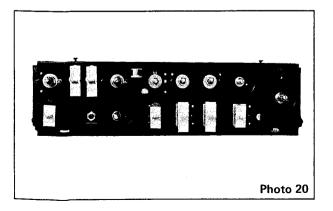
FRONT PANEL REMOVAL

- a. Remove screw 1 and loosen $2\sim5$ as shown in Photo 18. Then remove the shield board.
- b. Remove all knobs by pulling. Use a hexeagonal wrench to loosen the nots on the MODE, FUNCTION, TAPE and SPEAKER knobs.
- c. Remove screws 1~4 shown in Photo 19.

Note: The switch aprons are of varying sizes, so be careful not to confuse them during reinstallation. Install as shown in Photo 20.

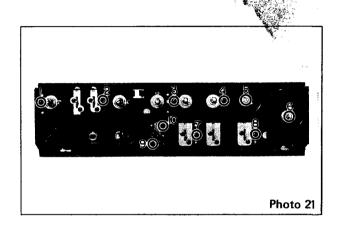


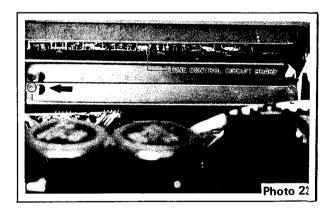


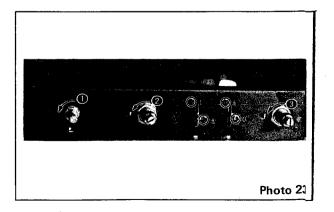


TONE CONTROL CIRCUIT BOARD REMOVAL

- a. Remove the front panel and tilt down the sub chassis.
- b. Remove screws 1~4 shown in Photo 21 and pull the circuit board with the shield case back to remove it.
- c. Loosen screws 1, 2 shown in Photo 22 and slide the shield case in the direction of the arrow to remove it.
- d. Pull out the CIS connector leading to the function circuit board.
- e. To separate the tone control circuit board from its holder, remove nuts 1~3 and screws 1~4 as shown in Photo 23.







VOLUME CIRCUIT BOARD REMOVAL

a. Remove the nuts 5, 6 shown in Photo 21, then pull the volume circuit board back to remove it.

FILTER CIRCUIT BOARD REMOVAL

- a. Remove the front panel and tilt down the sub chassis.
- b. Remove the tone control circuit board and shield
- c. Remove screws 7, 8 shown in Photo 21, then remove the filter circuit board and shield board.
- d. Remove two screws from the rear bottom of the filter circuit board shield board, then remove the filter circuit board.

OPERATION SWITCH CIRCUIT BOARD REMOVAL

- a. Remove the front panel and tilt the sub chassis forward.
- b. Pull off the two CIS connectors.
- c. Remove screws 9, 10 shown in Photo 21, then pull back the operation switch circuit board to remove it

POWER SWITCH CIRCUIT BOARD REMOVAL

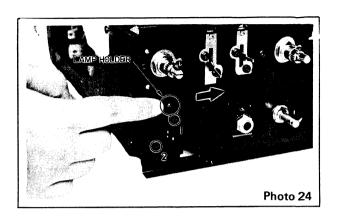
- a. Remove the front panel and tilt the sub chassis forward.
- b. Remove the tone control circuit board and shield case.
- c. Remove screws 1, 2 shown in Photo 24 and then remove the power switch circuit board.
- d. At this time, slide the lamp holder to the right as shown in Photo 25, and remove it. When reinstalling the pilot lamp, be careful that it is not placed too far forward so that it touches the front panel; it should not be too far from the lamp holder.

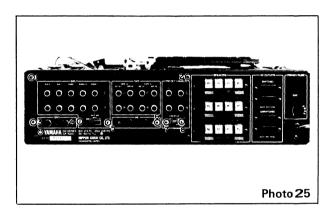
REAR PANEL CIRCUIT BOARD REMOVAL

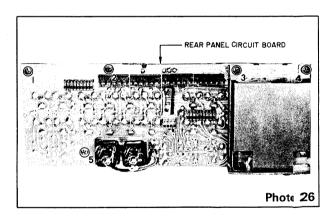
- a. Remove the function circuit board.
- b. Tilt the rear panel down.
- c., Pull out the CIS connector, and disconnect the chassis earth lead connected to chassis.
- d. Remove screws 1~8 as shown in Photo 25, then remove the rear panel circuit board.
- e. Remove screws $1\sim5$ as shown in Photo 26.
- f. If the rear panel circuit board is further disassembled, follow the procedure shown in Photo 27.

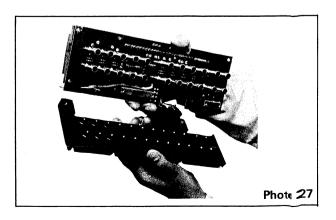
CABINET ASSEMBLY

- a. First put the power cord into the vabinet, then assembly it and the chassis, paying attention to the lead harness.
- b. When all parts are safely in the cabinet, reinstall the screws in reverse order. Lift the unit a bit to be sure of correct installation.









ADJUSTMENT OF EACH CIRCUIT BOARD

-BEFORE MEASUREMENT-

- Turn the Pre/Main amp. coupler switch Off.
- After the power switch is turned on, wait3~4 minutes before measuring, to be sure of the most

stable operation.

Do not connect speakers or dummy load resistance to the speaker terminals.

1. MAIN CIRCUIT BOARD

a. Primary Stage Differential Amplification Cir-

Set the voltage between TP1 and TP2 to 15V \pm 1V with VR602.

TP1 : (-)

TP2 : (+)

b. Mid-Point Potential Adjustment Set the voltage between SP Out terminal and E to $0V \pm 0.01V$ with VR601.

c. B Class Idling Current Adjustment
 Set the Operation switch to Normal.
 Set the voltage between TP3 and TP4 to 0.047V
 ± 0.01V with VR603.

TP3 : (+) TP4 : (-)

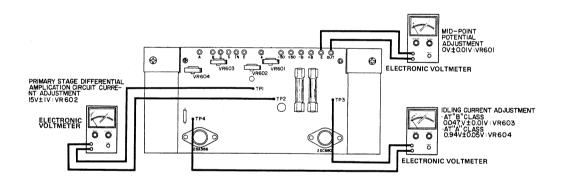
d. A Class Idling Current Adjustment
 Set the Operation switch to Class A.
 Set the voltage between TP3 and TP4 to 0.94V
 ±0.05V with VR604.

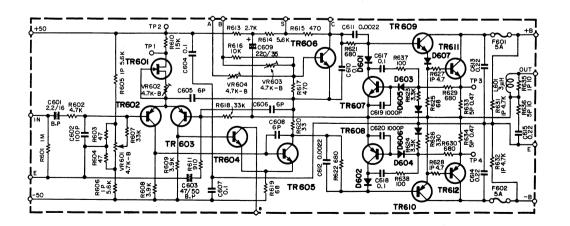
TP3 : (+) TP4 : (-)

e. Repeat procedures a-d above several times until each is within the allowable limits.

Turn the volume gently during adjustment.

 Pay close attention to the polarity of each test point.





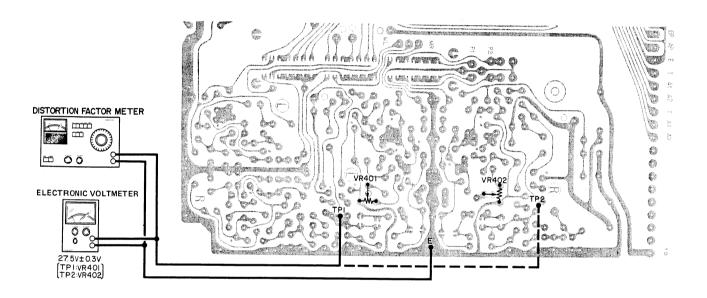
2. FUNCTION CIRCUIT BOARD

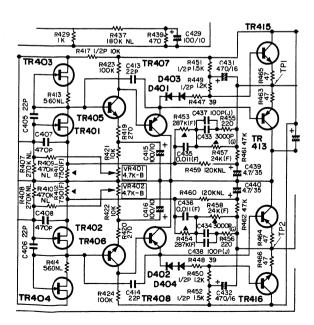
a. Equalizer SEPP Output Mid-Point Potential Adjustment.

The voltage between ,TP1 and TP2 on the circuit board and E should be $27.5V\pm0.3V$ (minimum potential distortion ratio).

Adjust TP1 with VR401, TP2 with VR402.

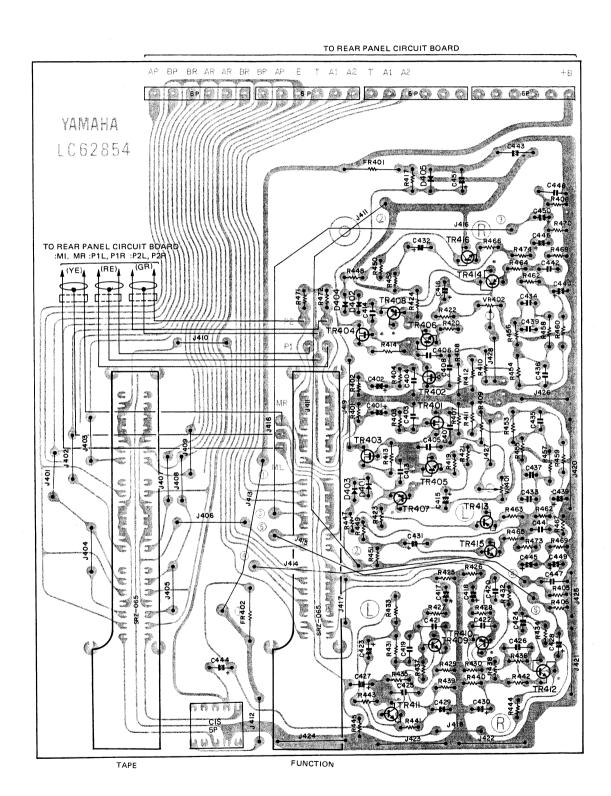
- Note: Turn the volume gently during adjustment
 - The Pre-Main coupler switch should be Off.





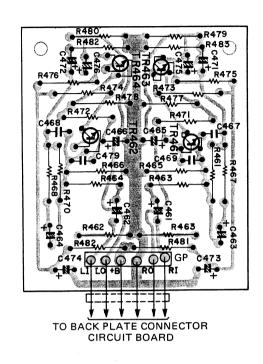
PRINTED CIRCUIT BOARDS

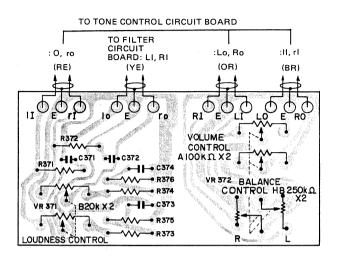
FUNCTION CIRCUIT BOARD NA06335



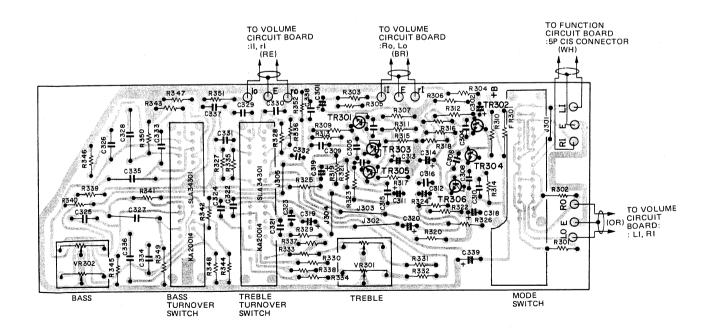
MC AMP. CIRCUIT BOARD NA06339

VOLUME CIRCUIT BOARD NA06336

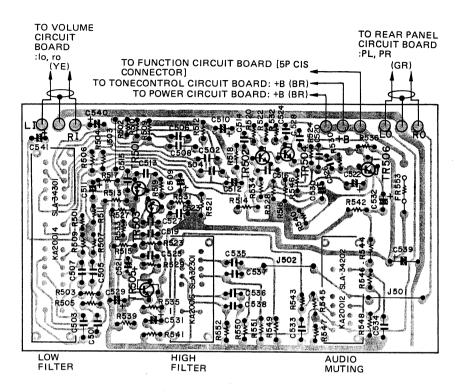




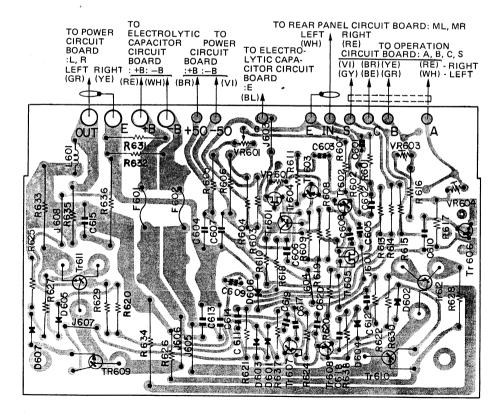
TONE CONTROL CIRCUIT BOARD NA06337



FILTER CIRCUIT BOARD NA06338

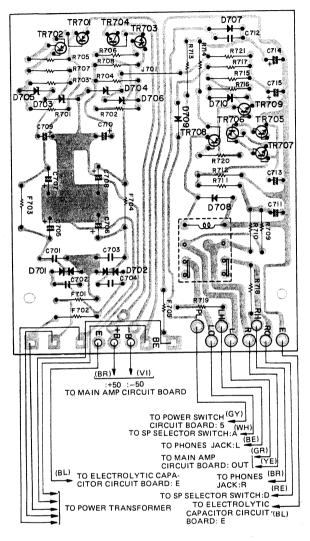


MAIN AMP. CIRCUIT BOARD NA06331

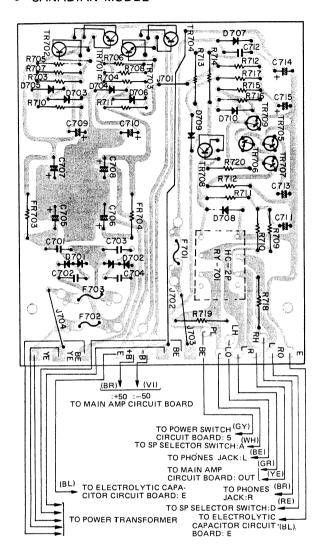


POWER CIRCUIT BOARD

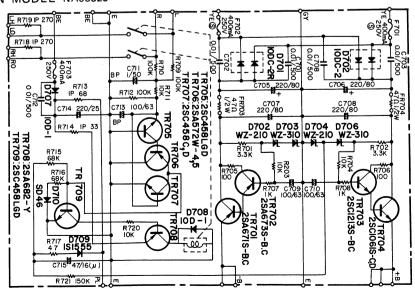
• EXCEPT CANADIAN MODEL NA06332



CANADIAN MODEL

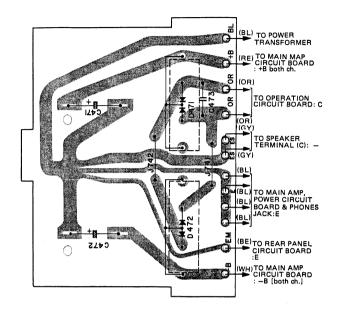


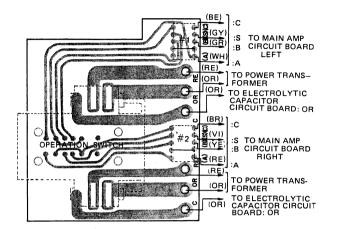
• CANADIAN MODEL NA06529



ELECTROLYTIC CAPACITOR CIRCUIT BOARD NA06352

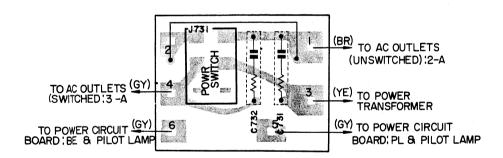
OPERATION CIRCUIT BOARD NA06354



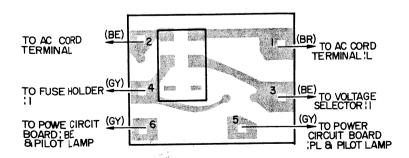


POWER SWITCH CIRCUIT BOARD.

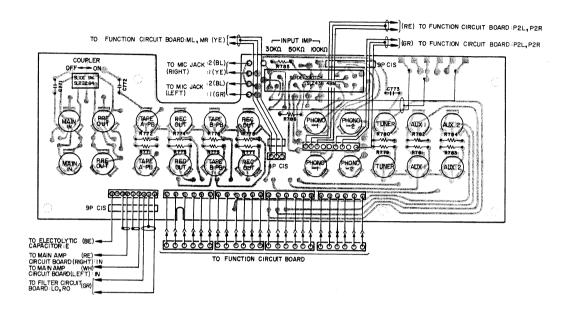
• EXCEPT EUROPEAN MODEL NA06375

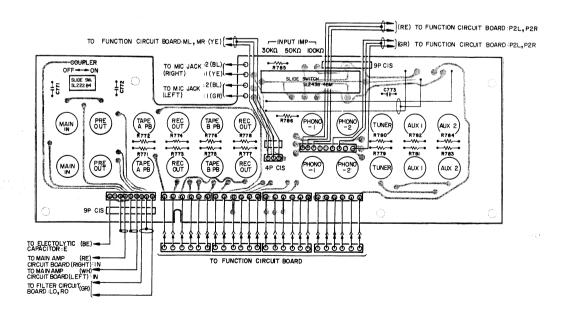


EUROPEAN MODEL NA06376

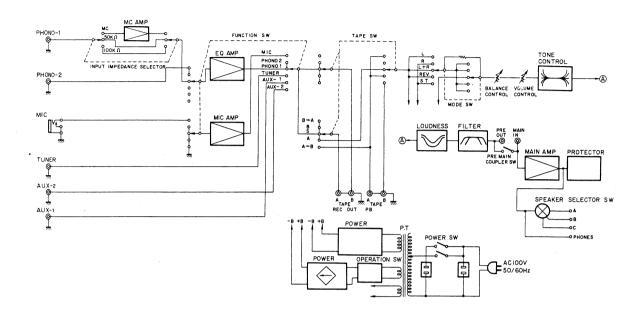


REAR PANEL CIRCUIT BOARD NA06333





BLOCK DIAGRAM



WIRE COLOR ABBREVIATIONS

BL ▶Black BR ▶ Brown VI ▶ Violet

RE ▶ Red

GY ▶ Gray

OR ▶ 0range

WH ▶ White

GG ▶ Light Green

YE ▶Yellow GR ▶Green

SB ▶ Light Blue

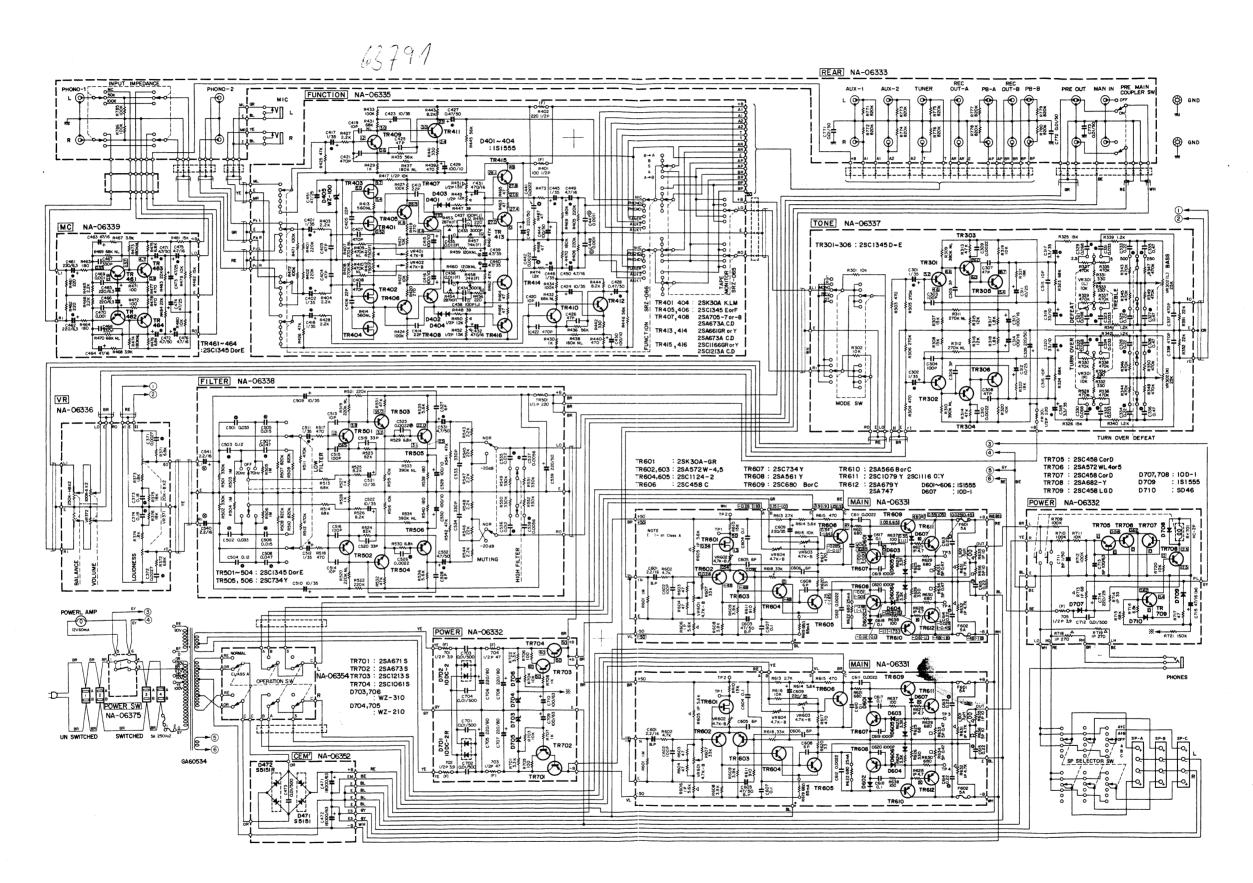
BE ▶Blue

PK ▶ Pink

SAMBOL	PARTS NAME
o—₩,—0	FUSE RESISTOR
Δ	METAL OXIDE RESISTOR
	CEMENT RESISTOR
NO MARK	CARBON RESISTOR
\boxtimes	CEMENT MOLDED RESISTOR
A	METALIZED FILM RESISTOR

SYMBOL	PARTS NAME	REMARKS
0	MYLAR CAPACITOR	
NO MARK	CERAMIC CAPACITOR	⊣⊢
0	POLYSTYRENE CAPACITOR	
NO MARK	(BI-POLAR) ELECTROLYTIC CAPACITOR	
•	LOW-NOISE ELECTROLYTIC CAPACITOR	
8	TANTALUM CAPACITOR	

OVERALL SCHEMATIC DIAGRAM

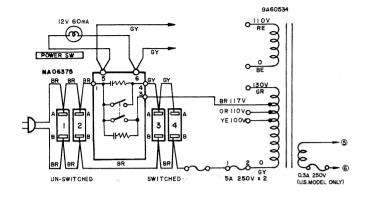


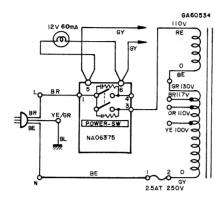
24

PARTIAL CHANGES MADE ACCORDING TO DISTINATION

• U.S. & CANADIAN MODELS

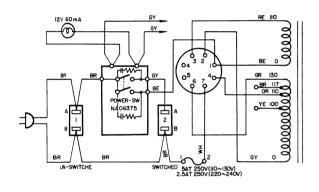
AUSTRALIAN MODEL

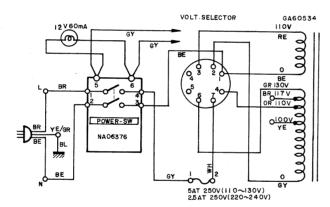




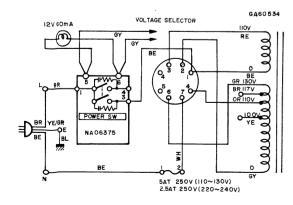
• GENERAL MODEL

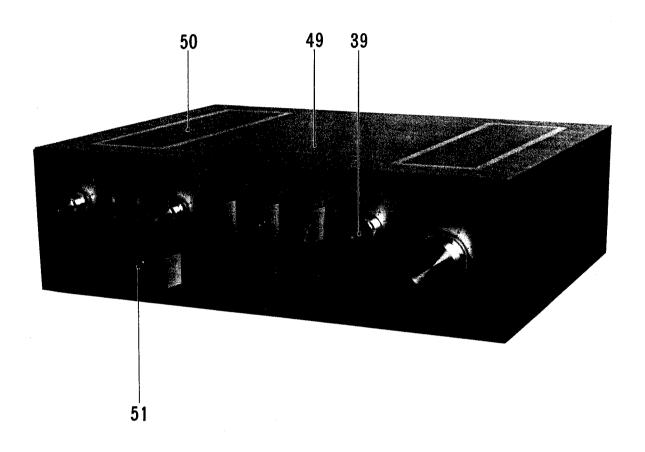


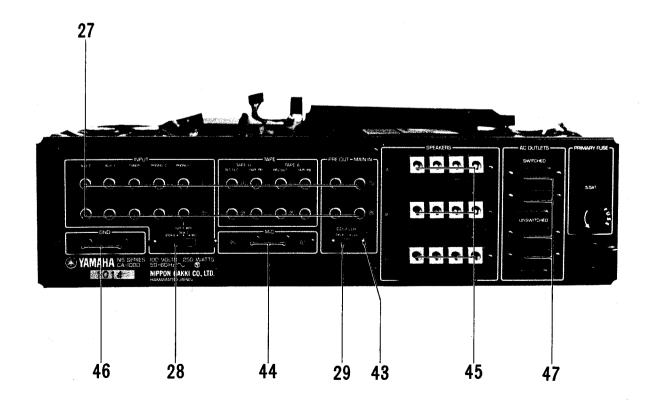


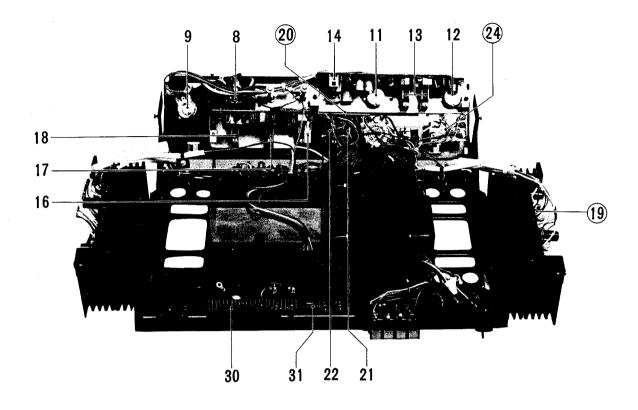


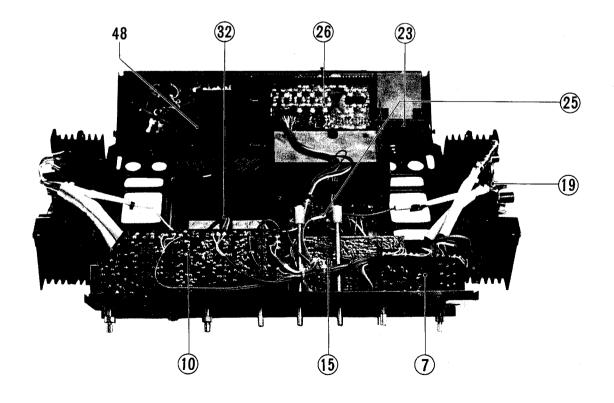
• SOUTH AFRICAN MODEL

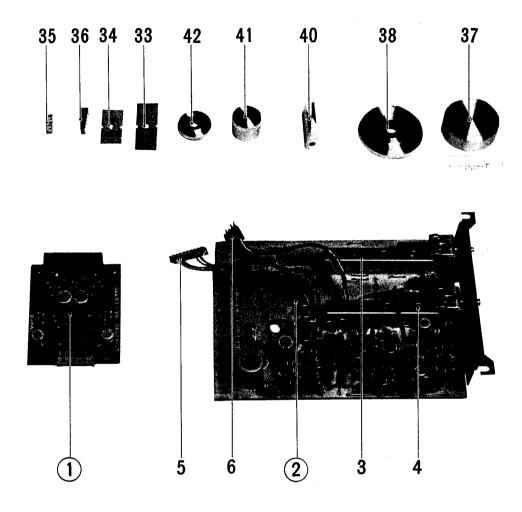












Ref. No.	Part No.	Description			Remarks	Common Models		
1	NA06339	MC AMP. Circuit board	#62891		MCアンプシート	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		
								_
	HE15768	Low Noise resistor	68K Ω ½	4W	ローノイズ抵抗			
	HE15818	**	180Κ Ω	"	"			
	FP51822	Tantalum capacitor	220 # F 6	i.3 WV	タンタル 固体コンデンサ			
	FP33647	"	4.7 # F 1	6 WV	"			
	EP16647	,,	4.7 µ F 5	60 WV	"			
					-			
	iC13454	Transistor	2SC1345 (D	or E)	トランジスタ			
								•
2	NA06335	FUNCTION Circuit board	d #62853		ファンクション シ - ト			
	NA06459	"	63790					
					金属被膜抵抗			
	HZ00028	Metalized Film resistor	750 Ω		"			
	HZ00019	,,	24ΚΩ		"			
	HZ00020		287ΚΩ					
	HL40612	Metal Oxide resistor	1.2ΚΩ		酸化金属抵抗			
	HL40615	"	1.5Κ Ω		"			
	HE15768	Low Noise resistor	68KΩ		ローノイズ抵抗			
	HE15818	"	180Κ Ω		"			
	HE15727	,,	270ΚΩ		"			
	HE15847	,,	470ΚΩ		"			
	HE15810	"	100ΚΩ					
	HZ00017	Fuse resistor	100 Ω	½ P	ヒューズ抵抗			
	HZ00014	"	220Ω	½ P	"			
	iF00004	Diode 1S1555			ダイオード			
	iF00028	Zener Diode WZ-210			ツェナーダイオード			
	FP54610	Tantalum capacitor	1 # F	25 V	タ ン タ ル コ ン デ ン サ			
	FP13647	"	4.7 µ F	16 WV	"			
	FP15610	"	1 # F	35 WV	"			
	FP16647	,,	4.7 μ F	50 WV	"			
	FP16547	"	0.47 μ F	50 WV	"			_
	FP15556	,,	0.56 μ F	35 WV	"			
	iA06613	Transistor	2SA661GR	(Y)	トランジスタ			
	iA06611		2SA661	(Y)	"	= 2SA673A		
	iC11662	"	2SC1166GR	(Y)	"	= 2SC1213A		
	iC13455	,,	2SC1345	(F or E)	"			
	iC13454	"	2SC1345	(D or E)	"			
	iE00004	Field Effect Transistor	2SK30A	(K, L or M)	電 解 効 果トランジスタ			

Ref. No.			Descrip		Remarks	Common Models		
	HT41004	Variable resistor	B4.7KΩ (SVK1	10R)	ソリッドボリウム			
-								
3	KA50028	Tape selector switch	SRZ-065		テープ切換スイッチ			
4	KA50027	Function Switch	SRZ-066		ファンクション 切 換 ス イ ッ チ			•
				• ••				
5	LB60028	6P connector	02145-6A		6 Pコネクター	1900		
6	LB50005	5P "	CIS socket		5 Pコネクター			
	LB10016	CIS Keying Pin			禁止ピン			
(7)	NA06336	VOLUME Circuit board	# 62861		ボリウムシート		CA-800 CA-600	
8	HS12034	Variable resistor	B20KΩx 2		ラウドネスボリウム			
9	HS12031	,,	HB250KΩ x 2, A	A100KΩ× 2	レ ベ ル 及 び バランスボリウム			
10	NA06337	TONE CONTROL Circuit	board #62874		トーンコントロール シー・ト			
	HE15827	Low Noise resistor	270Κ Ω	¼ W	ローノイズ抵抗			
	HE15839	"	390K Ω	"	"			
	HZ00014	Fuse resistor	220 Ω	½ W	ヒューズ抵抗			
					タンタル 田体			
	FP52733	Tantalum capacitor	33 # F	10 WV	タンタル 固体コン デンサ			
	FP15610	"	1 # F	35 WV	"			
	FP15633		3.3 μ F	"	"	****		
					11 点クリップ付			
11	HS12033	Variable resistor	8Z-10K x 2		11 点クリップ付ト レ ブ ル 用 11 点クリップ付			
12	HS12032		9Z-25 x 2		パニズ第	·		
			0004045 (D	·				
	iC13454	Transistor	2SC1345 (D oi	r E)	トランジスタ			
12	KA20014	Lever Switch	SLA-34301		ターンオーバー			
13	KA50029	Lever Switch	SRZ-045		ス イ ッ チ			
	17730029	"	J.1.2 0.10		こーで切換用			
(15)	NA06338	FILTER circuit board	# 62883		フィルターシート		CA800	
	HE15822	Low Noise resistor	220ΚΩ	1/4 W	ローノイズ抵抗			
-	HE15839	"	390KΩ	**	"			
	HZ00014	Fuse resistor	220 Ω	½ W	ヒューズ抵抗			
	FP13622	Tantalum capacitor (BP	type) 2.2 μ F	16 WV	タンタル 固体コンデンサ			·
	FP15610	,, (") 1 # F	35 WV	"			

Ref. No.	Part No.			Remarks	Common Models			
	FP16647	Tantalum capacitor (BP t	ype) 4.7 ^µ F	50 WV	タンタル 固体コンデンサ			
	iC07342	Transistor	2SC734 (Y)	-				
	iC13454	"	2SC1345 (D or	E)				
16	KA20014	Lever switch	SLA34301		ローフィルタース イッチ			
17	KA20012	,,	SLA34302		ス イ ッ チ ミューティング ス イ ッ チ			
18	KA20016	,,	SLA32301		ハイフィルター			
					スイッチ	-		
	NA06331	MAIN AMP Circuit board	# 62016		メインシート			
19	NA06331	MAIN AMP Circuit board	# 02010		7 1 2 2 1			
	11741015	Washington Davids and Advisory	DA 714 0 . 465	00141	半固定ボリウム			
	HT41015	Variable Resistor (Vert. ty	pe) B4./KΩ (SR-	29K)	干面をポリリム			
<u> </u>	HZ00021	Fire proofing resistor	4.7 Ω	1 W	不燃性抵抗			
	HL31410	Metal Oxide resistor	10 Ω	1 W	酸金抵抗			
	HL31647	"	4.7ΚΩ	"	"			
	HL31656	"	5.6ΚΩ	,,	"			
	HM55247	Cement resistor	0.47 Ω	5 W	セメント抵抗			
	HM55410	"	10 Ω	"	"	a. w. r. =		
	FM11747	BP capacitor (Vert. type)	2.2 # F	16 WV	バイポーラケミコン			
	FM09622	"	47 # F	50 WV	"			
	GD900005	Air core coil	3#H		空芯コイル			
	HZ00057	Fuse resistor	68 Ω	85 mA				
	HZ00060	"	680Ω	25 mA				
	iA05612	Transistor	2SA561 (Y)		トランジスタ			
	iA05662	"	2SA566 (B or	C)	"			
	iA05720	"	2SA572 (W-4.		,,			
	iC04583		2SC458		,,			
	iC06802	,,	2SC680 (B or	C)	"			
	iC07342	**	2SC734 (Y)	· · · · · · · · · · · · · · · · · · ·	"			
	iC11242	,,	2SC1124-2		"			
· · · · ·								
	iA07471	Power Transistor	2SA679Y or 2SA	 Δ747Υ	パ ワ - トランジスタ			
	iC11161	" Tansistor	2SC1079Y or 2S		トランジスタ			
	1011101		20010731 01 23	211101		***		
	;E00004	Diode	101555		ダイオード			
	iF00004	Diode	1\$1555		7 1 7 - F			

Ref. No.	Part No.	Descri		Remarks	Common Models		
	LB30011	Transistor socket S2-110B-00		トランジスタ ソ ケ ッ ト			
	BA06450	Heat Singk		放 熱 板			
<u> </u>	BB06308	Fixing metal		トランジスタプッシャー			
	LB20057	Fuse Holder-pin		ヒューズ ホルダーピン			

20	NA06354	OPERATION Circuit board #63091		オペレーションスイッチシート		CA800	
		·					
21	KA20012	Lever switch SLA34202		レバースイッチ			
22	KA60009	Micro switch V-10-1A		マイクロスイッチ			
	LB50005	CIS 5P socket		C I S 5 P ソ ケ ッ ト			-
	LB10016	CIS Keying pin		ソ ケ ッ ト CIS キーイング ピ ン			
	NB06636	Operation mechanism Ass'y		オペレーション 金 具 Assy			
23	NA06374	CONNECTOR Circuit board #63241		コネクターシート			
	LB60027	Morex connector-pin No.2183-6A		モ レ ッ ク スコネクターピン			
							, , , , , , , , , , , , , , , , , , , ,
24	NA06375	POWER SWITCH circuit board #63251		パワースイッチシート		CA-800, CA-600	
	KA20010	Power switch JL-04		パワースイッチ			
	FZ00011	Spark Killer 0.003 \(\mu \) F x	120 Ω	スパークキラー			
						· · · · · ·	
25	NA06332	POWER Circuit board #62823		電源シート		CA-800	
				ヒューズ		*	
	HZ00016	Fuse resistor 3.9 Ω	½ W	抵抗	* ***		
	HZ00015	" 47 Ω		"			
		Maria 0 14 - 200	4 141	x / / /			
	HL41433	Metal Oxide resistor 33 Ω	1 W	酸化金属抵抗			
	HL41468	" 68 Ω	"	,			
	HL41527	,, 270 Ω		,,			
		P1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	E 16 W/V		ku tuna		
-	-	Electrolytic capacitor (Vert type) 47 μ	L 10 WV		ku type		
	FN440040	BP capacitor 100 # F	6.3 WV	バイポーラ			
	FM10810		50 WV	ケミコン			
	FM11610	" 1 # F	DO AAA	<u> </u>			
		n 1	121/	リレー			
	KC00008	Relay HC-2P DC-1	12 V				

Ref. No.	Part No.	Descriptio	o n	Remarks	Common Models	
	iA05720	Transistor 2SA572 (W-4.5)	トランジスタ			
	iA06719	" 2SA671S (B or C)	,,			
	iA06739	" 2SA673S (B or C)	,,			
	iA06820	" 2SA682 (Y)	"		_	
	iC04583	" 2SC458 (C or D)	"			
	iC10618	" 2SC1061S (C or D) "			
	iC12139	" 2SC1213S (B or C) "			
	IC0456	" 2SC458 Lg.D				
	iH00003	Diode 10D-1	ダイオード			
	iH00005	" 10DC-2	"			
	iH00013	" 10DC-2R	"	· · ·		· · · · · · · · · · · · · · · · · · ·
	iF00004	" 1S1555	"			
	iF00002	" SD-46	"			
	iF00028	Zener Diode WZ-210	ツ ェ ナ <u>-</u> ダ イ ォ ー ド			
	iF00022	" WZ-310	/ / / / / / / / / / / / / / / / / / /			
				-		
26	NA06333	REAR PANEL Circuit board #62835	リャパネルシート			
			/ - F		-	
27	LB10014	Pin Jack (for Circuit board)	プリント基板 用ピン ジャック			
	LB60027	Connector Pin	コネクターピン			
28	KA40020	Slide switch (Phono) SL243B4BM	フォノインピー ダ ンス切換用スイッチ			
29	KA40021	" (Coupler) SL222B4	カプラースイッチ			

30	LB40008	CIS 4P Connector Socket	C I S 4 P コネクターソケット			,
31	LB60025	CIS 9P Connector Socket	C I S 5 P コネクターソケット			
	LB10016	CIS Keying Pin	禁止 ピン			
32)	NA06352	ELECTROLYTIC CAPACITOR Circuit board	#63181 ケミコンシート	·		
	FZ00012	Electrolytic capacitor (Lug type) 1800 # F	63 WV 電解コンデンサ			
	iH00021	Silicon Diode S-5151 (RED)	シリコン整流器			
	iH00022	" S5151R (BLACK)	,,			
	CB06964	Rubber Spacer	ゴムスペーサ			
				 		
	 				+	
	1	<u> </u>				

Ref. No.	Part No.	Description	Remarks	Common Models	
	NB06610	Front Panel Unit	フ ロ ン ト パネルユニット		
	NB06614	Rear Panel Unit (with Circuit board)	リヤパネルユニット		
33	CB06873	Switch apron 15 x 42	スイッチエプロン		CA800
34	CB06872	" 15 x 29	"		CA800
35	CB06858	Switch Bush	ス イ ッ チ 用 ブ ッ シ ュ		
36	CB06857	Knob (for Lever Switch)	レバースイッチ用 ツ マ ミ		CA800 CR-400
37	BA06443	Double Knob (Level)	ダブルツマミ		CA800
38	BA06448	" (Balance)	"		CA800
39	BA06446	Knob (Loudness)	ツマミ		CA800
40	BA06442	Switch Knob (Mode, Tape, Function)	スイッチツマミ		CA800
41	BA06444	Double Knob (Tone Left ch.)	ダブルツマミ		CA800
42	BA06447	" (Tone Right ch.)	"		CA800
	CB06861	Lamp lens	ランプレンズ		CA800
	CB06827	Phone nut	ホーンナット		
	CB06862	Lamp holder	ランプホルダー		
43	CB06868	Coupler stopper	カプラー		
	CB06851	Rear Panel Circuit Board Protector	リヤパネル		
	CB06863	Cord stopper HEYCO SR-3P-4	シートプロテクター コードストッパ	General, U.S. & Canadian	CA800
	CB00441	" 0661006	"	Models South African, Australian	CA800
	JB00023	Lead Type Lamp 12V 60mA	リード式ランプ	& European Models	JA000
44	LB30008	Phone Jack (Mic) SG7822	ホーンジャック		
45	LA00111	4PD Type Push-terminal	4 P D 型		
46	LA00111	Ground terminal	プッシュターミナル ア ー ス 端 子		
40	'_B20030	AC Socket	アース 端 子 A C コンセント		
	-B20030	AC SOCKET	701757		
48	GA60530	Power Transformer	電源トランス		
49	DC6048Z	Outside case	外 装 本 体		CA800
	AA07308	Punching Metal	パンチングメタル		
50	AA07354	Radiator grill	放熱グリル		
	CB06855	Leg	脚		
	NB06675	Pad	サービスパッド		
51	LB30007	Phone Jack (Head-phone) JH-5020K	ヘッドフォン用 ジャック		
	LB20025	Voltage Selector	電圧切換器		
	LB20044	Fuse Holder	ヒューズホルダー	Except European Model	
	LB20059	n .	"	European Model	
	+				